## NSN 5962-01-348-7399

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View Online at https://aerobasegroup.com/nsn/5962-01-348-7399

Overall Height:
0.400 inches
Overall Width:
Between 0.290 inches and 0.320 inches
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
650.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
1260-01-165-3959
Features Provided:
Bidirectional and burn in and electrostatic sensitive and erasable and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital erasable, programmable logic device
Voltage Rating And Type Per Characteristic:
-2.0 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
55.00 nanoseconds access
Memory Device Type:
Pal
Hybrid Technology Type:

Monolithic

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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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